TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (L^2 - π -MOSV)

2SK2313

Chopper Regulator, DC-DC Converter and Motor Drive Applications

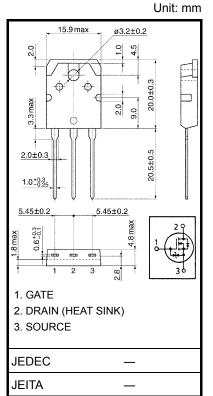
• 4-V gate drive

• Low drain-source ON resistance : R_{DS} (ON) = 8 m Ω (typ.) • High forward transfer admittance : $|Y_{fs}| = 60 \text{ S (typ.)}$ • Low leakage current : $I_{DSS} = 100 \text{ } \mu\text{A (max)}$ ($V_{DS} = 60 \text{ V}$)

• Enhancement mode : $V_{th} = 0.8 \text{ to } 2.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

| Characteri | stics | Symbol | Rating | Unit |
|---------------------------|------------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 60 | V |
| Drain-gate voltage (R | _{GS} = 20 kΩ) | V_{DGR} | 60 | V |
| Gate-source voltage | | V_{GSS} | ±20 | V |
| Drain current | DC (Note 1) | ΙD | 60 | Α |
| | Pulse (Note 1) | I_{DP} | 240 | Α |
| Drain power dissipatio | n (Tc = 25°C) | P_{D} | 150 | W |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 1054 | mJ |
| Avalanche current | | I _{AR} | 60 | Α |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 15 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature range | | T _{stg} | -55 to 150 | °C |



2-16C1B

Weight: 4.6 g (typ.)

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Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 398 μH , $R_{G} = 25 \Omega$, $I_{AR} = 60 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

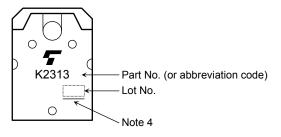
Electrical Characteristics (Ta = 25°C)

| Charac | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|----------------------|--|-----|------|-----|------|
| Gate leakage cu | irrent | I _{GSS} | V _{GS} = ±16 V, V _{DS} = 0 V | _ | _ | ±10 | μΑ |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 60 V, V _{GS} = 0 V | _ | _ | 100 | μΑ |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 60 | _ | _ | V |
| Gate threshold v | /oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 0.8 | _ | 2.0 | V |
| Drain-source ON resistance | | R _{DS (ON)} | V _{GS} = 4 V, I _D = 30 A | _ | 12 | 15 | 0 |
| | | | V _{GS} = 10 V, I _D = 30 A | | 8 | 11 | mΩ |
| Forward transfer | r admittance | Y _{fs} | V _{DS} = 10 V, I _D = 30 A | 40 | 60 | _ | S |
| Input capacitano | e | C _{iss} | | | 5400 | _ | |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | | 920 | _ | pF |
| Output capacitance | | Coss | | _ | 2600 | _ | |
| Switching time | Rise time | t _r | $V_{GS} = \frac{10V}{0V}$ $V_{GS} = \frac{10V}{0V}$ V_{OUT} $V_{DD} = 30V$ $V_{DD} = 30V$ $V_{DD} = 30V$ | _ | 30 | _ | |
| | Turn-on time | t _{on} | | _ | 60 | _ | - ns |
| | Fall time | t _f | | _ | 65 | _ | |
| | Turn-off time | t _{off} | | _ | 220 | _ | |
| Total gate charge (Gate-source plus gate-drain) | | Qg | | _ | 170 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 48 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 60 \text{ A}$ | | 110 | | nC |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 60 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 60 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 240 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 60 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 60 A, V _{GS} = 0 V dI _{DR} / dt = 50 A / μs | _ | 150 | _ | ns |
| Reverse recovered charge | Q _{rr} | | _ | 0.3 | _ | μC |

Marking

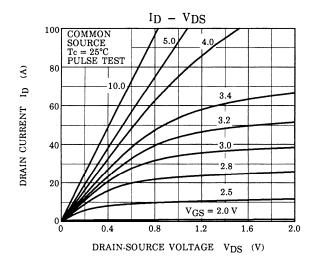


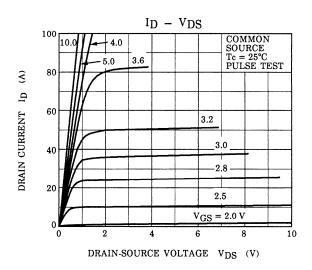
Note 4: A line under a Lot No. identifies the indication of product Labels.

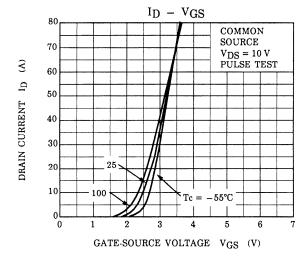
Not underlined: [[Pb]]/INCLUDES > MCV

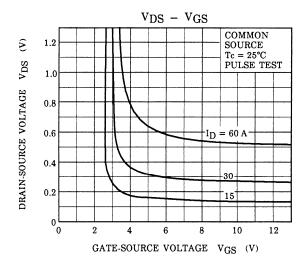
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

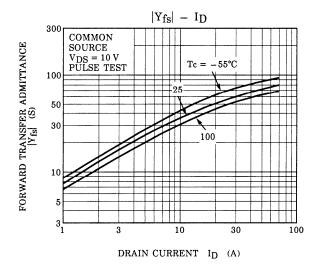
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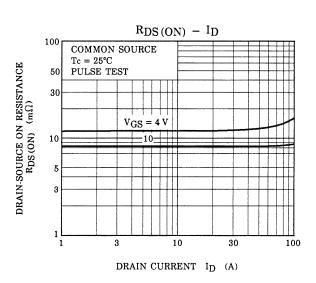




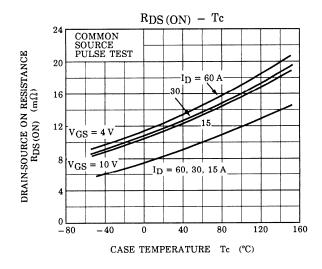


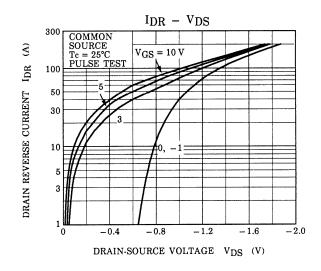


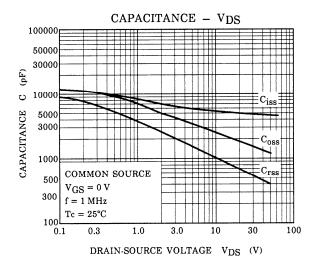


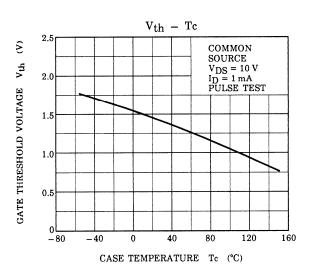


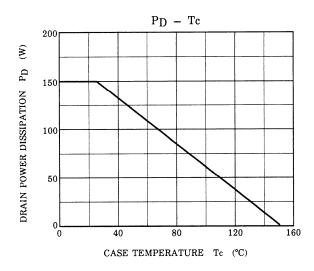
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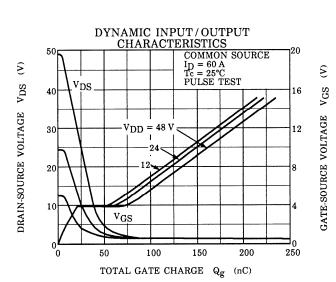




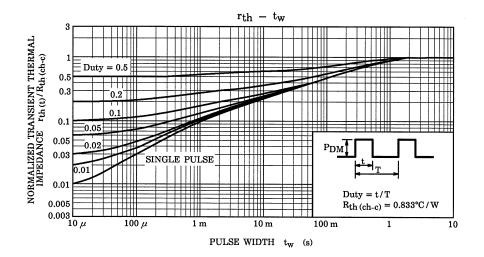


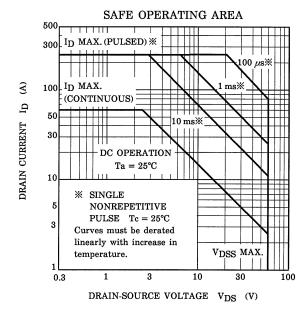


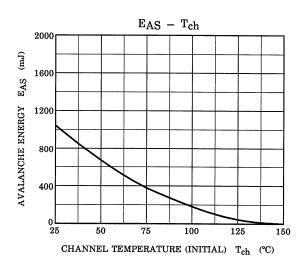


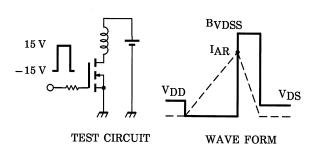


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$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 25~V,~L = 398~\mu H \end{aligned} \qquad EAS &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right) \end{aligned}$$

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